



## GaAs InGaP HBT MMIC POWER AMPLIFIER, 5 - 7 GHz

### Typical Applications

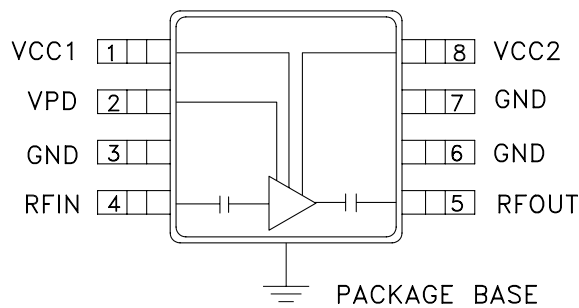
This amplifier is ideal for use as a power amplifier for 5 - 7 GHz applications:

- UNII
- HiperLAN

### Features

Gain: 15 dB  
Saturated Power: +29 dBm  
28% PAE  
Supply Voltage: +5V  
Power Down Capability  
No External Matching Required

### Functional Diagram

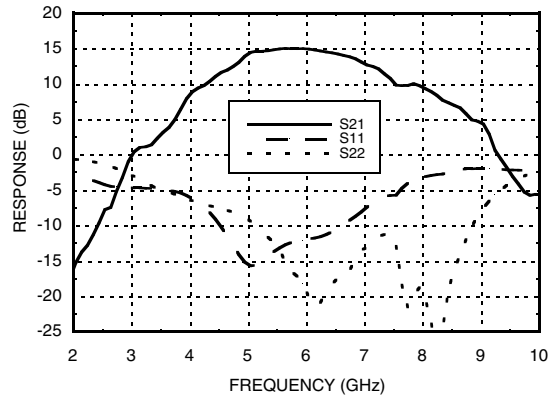
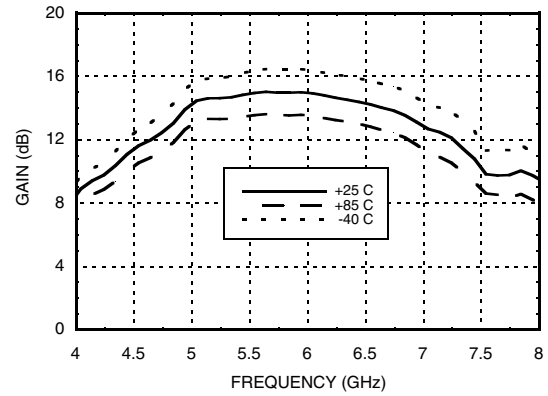
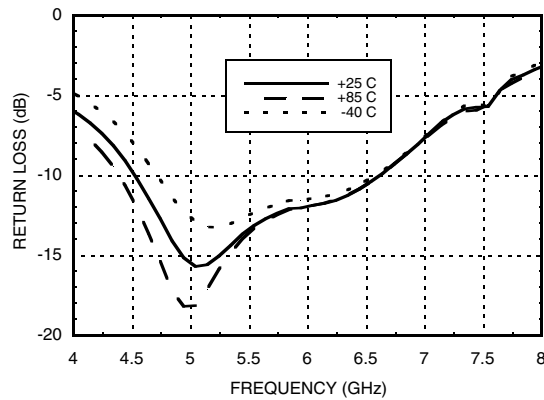
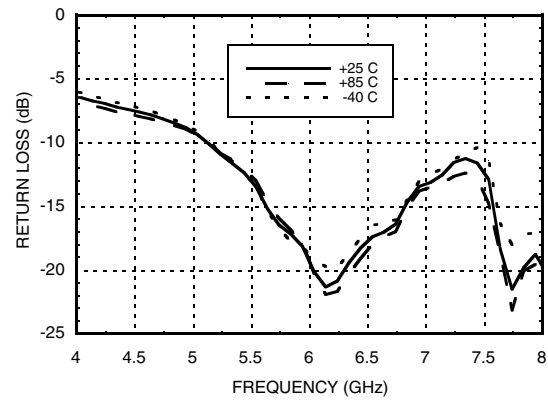
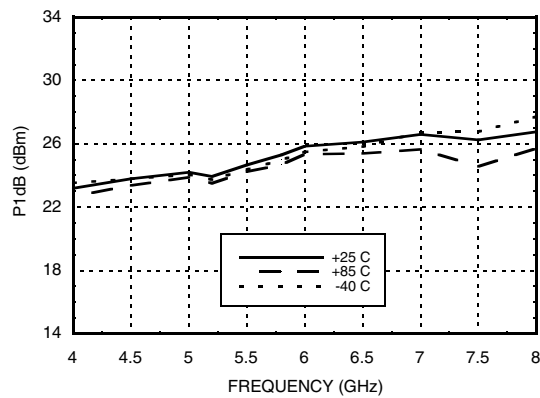
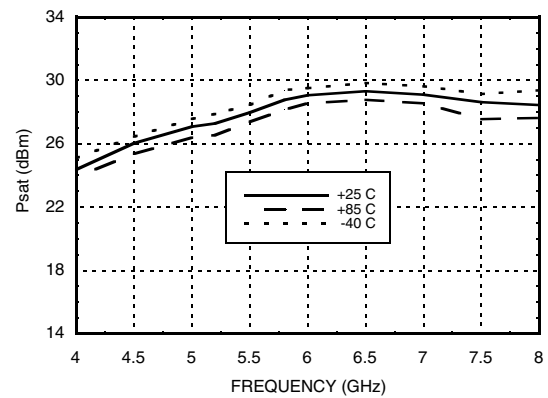


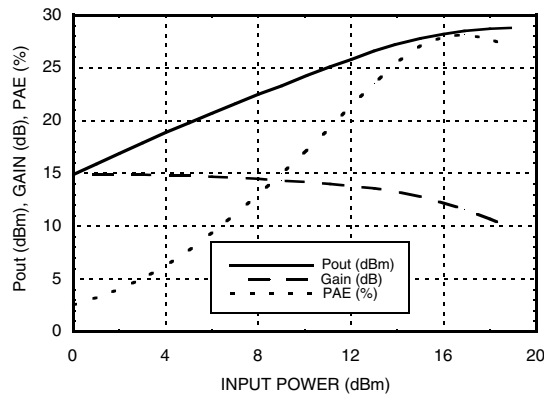
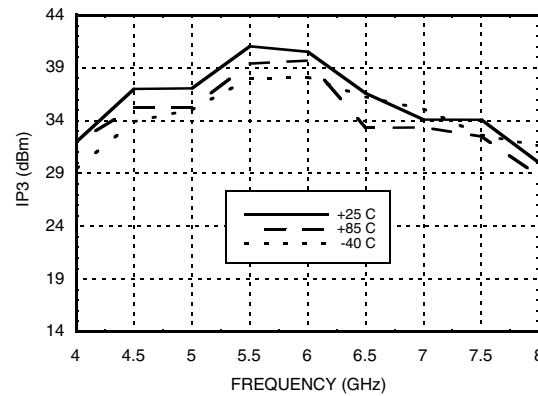
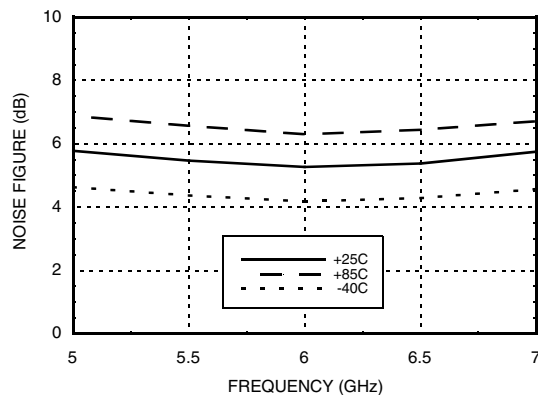
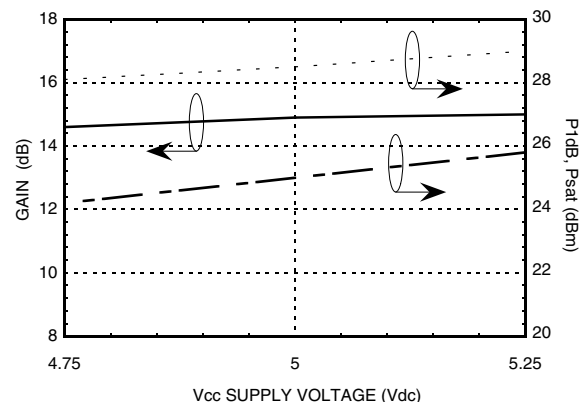
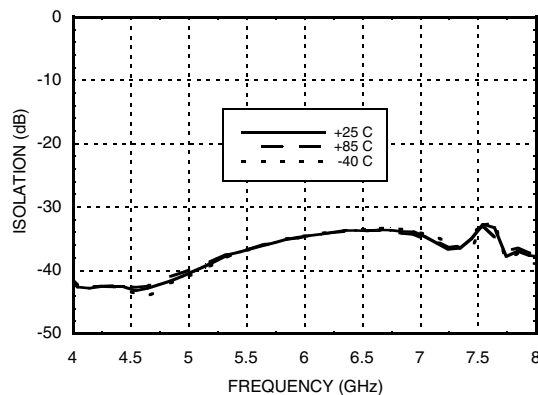
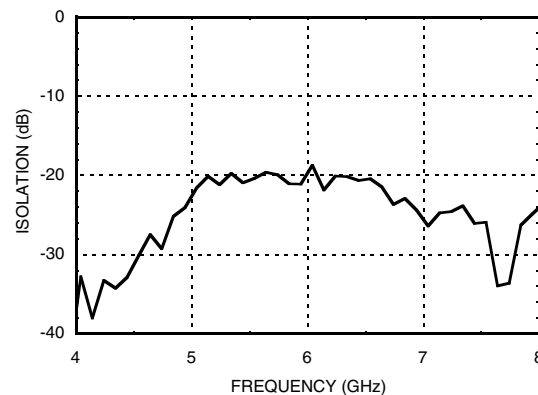
### General Description

The HMC407MS8G & HMC407MS8GE are high efficiency GaAs InGaP Heterojunction Bipolar Transistor (HBT) MMIC Power amplifiers which operate between 5 and 7 GHz. The amplifier requires no external matching to achieve operation and is thus truly 50 Ohm matched at input and output. The amplifier is packaged in a low cost, surface mount 8 leaded package with an exposed base for improved RF and thermal performance. The amplifier provides 15 dB of gain, +29 dBm of saturated power at 28% PAE from a +5V supply voltage. Power down capability is available to conserve current consumption when the amplifier is not in use.

### Electrical Specifications, $T_A = +25^\circ \text{C}$ , $V_s = 5\text{V}$ , $V_{pd} = 5\text{V}$

| Parameter                                | Min.                           | Typ.  | Max.  | Min.        | Typ.  | Max.  | Units  |
|------------------------------------------|--------------------------------|-------|-------|-------------|-------|-------|--------|
| Frequency Range                          | 5 - 7                          |       |       | 5.6 - 6.0   |       |       | GHz    |
| Gain                                     | 10                             | 15    | 18    | 12          | 15    | 18    | dB     |
| Gain Variation Over Temperature          |                                | 0.025 | 0.035 |             | 0.025 | 0.035 | dB/ °C |
| Input Return Loss                        |                                | 12    |       |             | 12    |       | dB     |
| Output Return Loss                       |                                | 15    |       |             | 15    |       | dB     |
| Output Power for 1 dB Compression (P1dB) | 21                             | 25    |       | 22          | 25    |       | dBm    |
| Saturated Output Power (Psat)            |                                | 29    |       |             | 29    |       | dBm    |
| Output Third Order Intercept (IP3)       | 32                             | 37    |       | 36          | 40    |       | dBm    |
| Noise Figure                             |                                | 5.5   |       |             | 5.5   |       | dB     |
| Supply Current (Icq)                     | $V_{pd} = 0\text{V}/5\text{V}$ |       |       | 0.002 / 230 |       |       | mA     |
| Control Current (Ipd)                    | $V_{pd} = 5\text{V}$           |       |       | 7           |       |       | mA     |
| Switching Speed                          | $t_{ON}, t_{OFF}$              |       |       | 30          |       |       | ns     |

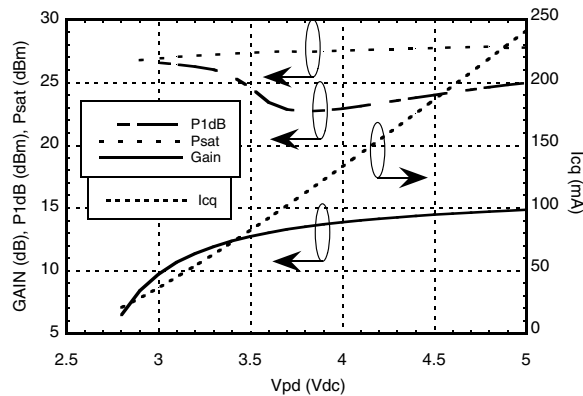
**Broadband Gain & Return Loss**

**Gain vs. Temperature**

**Input Return Loss vs. Temperature**

**Output Return Loss vs. Temperature**

**P1dB vs. Temperature**

**Psat vs. Temperature**


**Power Compression @ 5.8 GHz**

**Output IP3 vs. Temperature**

**Noise Figure vs. Temperature**

**Gain & Power vs. Supply Voltage**

**Reverse Isolation vs. Temperature**

**Power Down Isolation**




## GaAs InGaP HBT MMIC POWER AMPLIFIER, 5 - 7 GHz

### Gain, Power & Quiescent Supply Current vs. Vpd @ 5.8 GHz



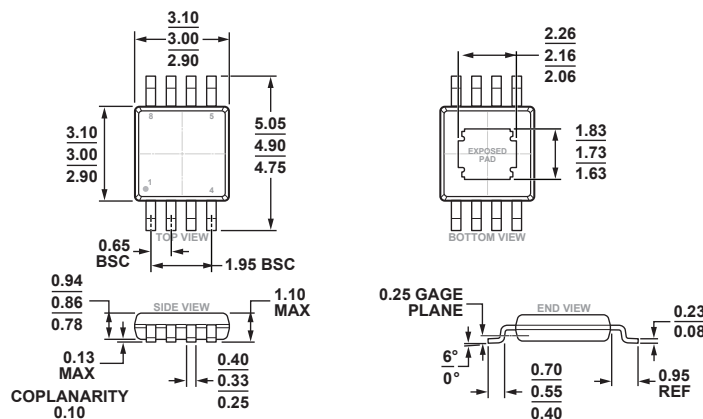
### Absolute Maximum Ratings

|                                                              |                |
|--------------------------------------------------------------|----------------|
| Collector Bias Voltage (Vcc1, Vcc2)                          | +5.5 Vdc       |
| Control Voltage (Vpd)                                        | +5.5 Vdc       |
| RF Input Power (RFIN)(Vs = Vpd = +5Vdc)                      | +20 dBm        |
| Junction Temperature                                         | 150 °C         |
| Continuous Pdis (T = 85 °C)<br>(derate 31 mW/°C above 85 °C) | 2 W            |
| Thermal Resistance<br>(junction to ground paddle)            | 32 °C/W        |
| Storage Temperature                                          | -65 to +150 °C |
| Operating Temperature                                        | -40 to +85 °C  |



ELECTROSTATIC SENSITIVE DEVICE  
OBSERVE HANDLING PRECAUTIONS

### Outline Drawing



COMPLIANT TO JEDEC STANDARDS MO-187-AA-T

8-Lead Mini Small Outline Package with Exposed Pad [MINI\_SO\_EP]  
(RH-8-1)

Dimensions shown in millimeters

### Package Information

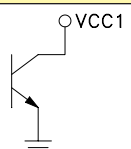
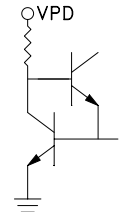
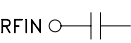
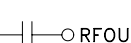
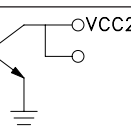
| Part Number           | Package Body Material                              | Lead Finish   | MSL Rating          | Package Marking <sup>[3]</sup> |
|-----------------------|----------------------------------------------------|---------------|---------------------|--------------------------------|
| HMC407MS8G            | Low Stress Injection Molded Plastic                | Sn/Pb Solder  | MSL1 <sup>[1]</sup> | H407<br>XXXX                   |
| HMC407MS8GE           | RoHS-compliant Low Stress Injection Molded Plastic | 100% matte Sn | MSL1 <sup>[2]</sup> | H407<br>XXXX                   |
| HMC407MS8GETR         | RoHS-compliant Low Stress Injection Molded Plastic | 100% matte Sn | MSL1 <sup>[2]</sup> | H407<br>XXXX                   |
| HMC407MS8GTR          | Low Stress Injection Molded Plastic                | Sn/Pb Solder  | MSL1 <sup>[1]</sup> | H407<br>XXXX                   |
| 104987-<br>HMC407MS8G | Eval Board                                         |               |                     |                                |

[1] Max peak reflow temperature of 235 °C

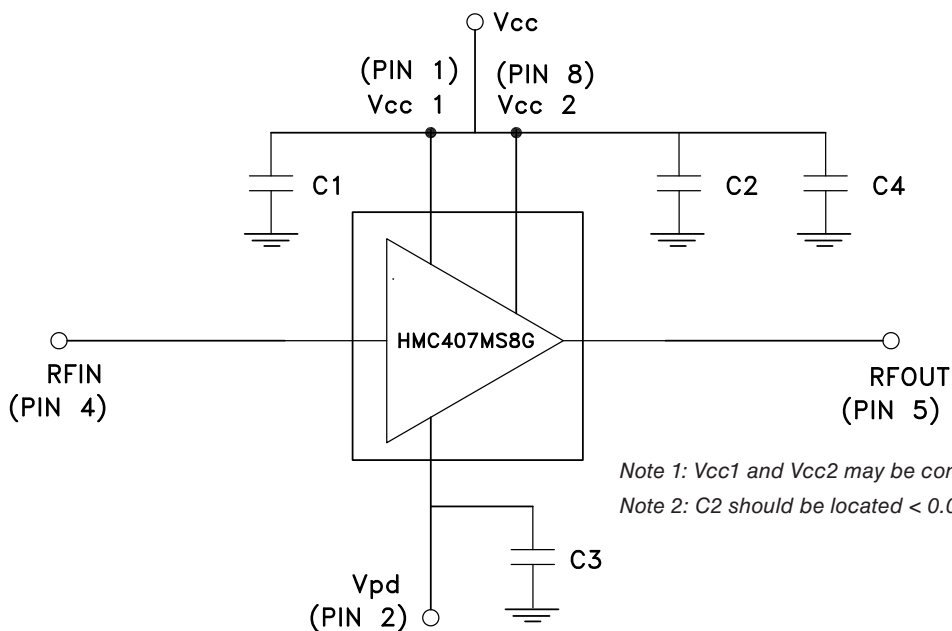
[2] Max peak reflow temperature of 260 °C

[3] 4-Digit lot number XXXX

## Pin Descriptions

| Pin Number | Function | Description                                                                                                                                                                      | Interface Schematic                                                                   |
|------------|----------|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|---------------------------------------------------------------------------------------|
| 1          | Vcc1     | Power supply voltage for the first amplifier stage. An external bypass capacitor of 330 pF is required as shown in the application schematic.                                    |    |
| 2          | Vpd      | Power control pin. For maximum power, this pin should be connected to 5V. A higher voltage is not recommended. For lower die current, this voltage can be reduced.               |    |
| 3, 6, 7    | GND      | Ground: Backside of package has exposed metal ground slug that must be connected to ground thru a short path. Vias under the device are required.                                |    |
| 4          | RFIN     | This pin is AC coupled and matched to 50 Ohms.                                                                                                                                   |    |
| 5          | RFOUT    | This pin is AC coupled and matched to 50 Ohms.                                                                                                                                   |   |
| 8          | Vcc2     | Power supply voltage for the output amplifier stage. An external bypass capacitor of 330 pF is required. This capacitor should be placed no more than 20 mils from package lead. |  |

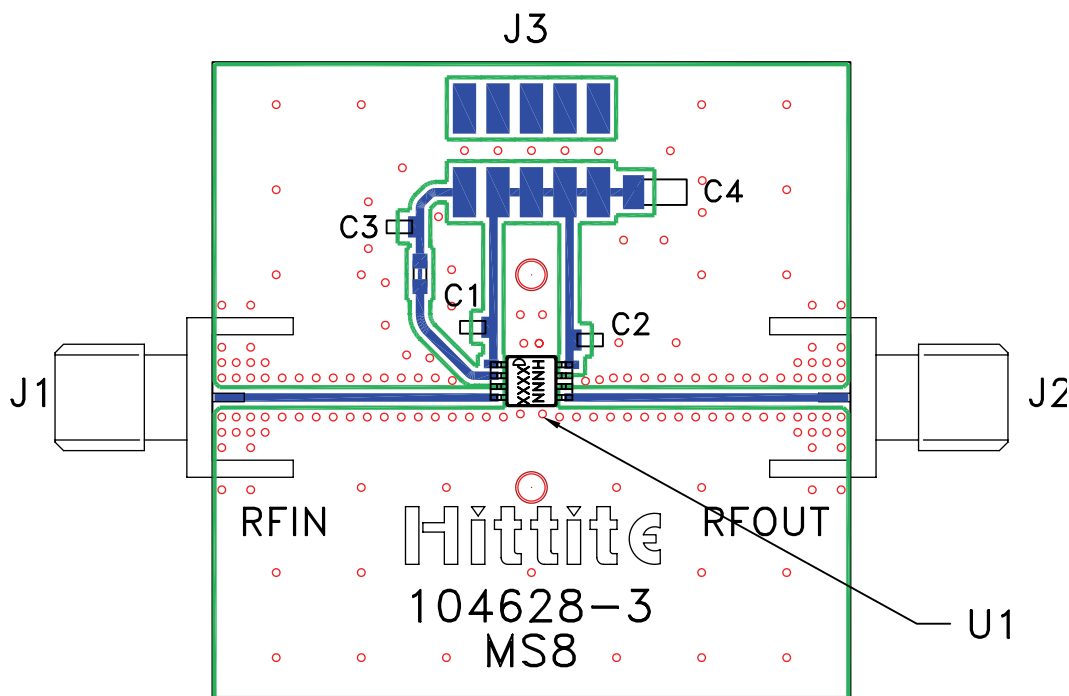
## Application Circuit



Note 1: Vcc1 and Vcc2 may be connected to a common Vcc.

Note 2: C2 should be located < 0.020" from Pin 8 (Vcc2).

**Evaluation PCB**



**List of Materials for Evaluation PCB 104987 <sup>[1]</sup>**

| Item               | Description                        |
|--------------------|------------------------------------|
| J1 - J2            | PCB Mount SMA RF Connector         |
| J3                 | 2 mm DC Header                     |
| C1 - C3            | 330 pF Capacitor, 0603 Pkg.        |
| C4                 | 2.2 $\mu$ F Capacitor, Tantalum    |
| U1                 | HMC407MS8G / HMC407MS8GE Amplifier |
| PCB <sup>[2]</sup> | 104628 Eval Board                  |

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Roger 4350

The circuit board used in the final application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation board should be mounted to an appropriate heat sink. The evaluation circuit board shown is available from Analog Devices, upon request.

Компания «Океан Электроники» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Поставка оригинальных импортных электронных компонентов напрямую с производств Америки, Европы и Азии, а так же с крупнейших складов мира;
- Широкая линейка поставок активных и пассивных импортных электронных компонентов (более 30 млн. наименований);
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Помощь Конструкторского Отдела и консультации квалифицированных инженеров;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Поставка электронных компонентов под контролем ВП;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- При необходимости вся продукция военного и аэрокосмического назначения проходит испытания и сертификацию в лаборатории (по согласованию с заказчиком);
- Поставка специализированных компонентов военного и аэрокосмического уровня качества (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Actel, Aeroflex, Peregrine, VPT, Syfer, Eurofarad, Texas Instruments, MS Kennedy, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Компания «Океан Электроники» является официальным дистрибьютором и эксклюзивным представителем в России одного из крупнейших производителей разъемов военного и аэрокосмического назначения «JONHON», а так же официальным дистрибьютором и эксклюзивным представителем в России производителя высокотехнологичных и надежных решений для передачи СВЧ сигналов «FORSTAR».



## JONHON

«JONHON» (основан в 1970 г.)

Разъемы специального, военного и аэрокосмического назначения:

(Применяются в военной, авиационной, аэрокосмической, морской, железнодорожной, горно- и нефтедобывающей отраслях промышленности)

«FORSTAR» (основан в 1998 г.)

ВЧ соединители, коаксиальные кабели,  
кабельные сборки и микроволновые компоненты:

(Применяются в телекоммуникациях гражданского и специального назначения, в средствах связи, РЛС, а так же военной, авиационной и аэрокосмической отраслях промышленности).



Телефон: 8 (812) 309-75-97 (многоканальный)

Факс: 8 (812) 320-03-32

Электронная почта: [ocean@oceanchips.ru](mailto:ocean@oceanchips.ru)

Web: <http://oceanchips.ru/>

Адрес: 198099, г. Санкт-Петербург, ул. Калинина, д. 2, корп. 4, лит. А